- **Inputs Are TTL-Voltage Compatible**
- **EPIC™ (Enhanced-Performance Implanted CMOS) Process**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) DIPs**

SN54AHCT244 . . . J OR W PACKAGE
SN74AHCT244 . . . DB, DGV, DW, N, OR PW PACKAGE
(TOP VIEW)

1OE	1	20	V_CC
1A1	2	19	2OE
2Y4	3	18	1Y1
1A2	4	17	2A4
2Y3	5	16	1Y2
1A3	6	15	2A3
2Y2	7	14	1Y3
1A4	8	13	2A2
2Y1	9	12	1Y4
GND	10	11	2A1
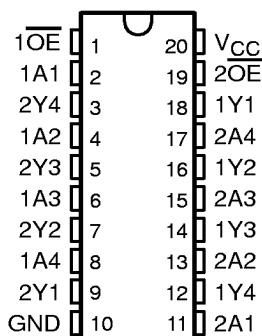
SN54AHCT244 . . . FK PACKAGE
(TOP VIEW)

description

These octal buffers/drivers are designed specifically to improve both the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

The 'AHCT244 devices are organized as two 4-bit buffers/line drivers with separate output-enable (OE) inputs. When OE is low, the device passes data from the A inputs to the Y outputs. When OE is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down, OE should be tied to V_CC through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54AHCT244 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74AHCT244 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE
(each buffer/driver)

INPUTS		OUTPUT
OE	A	Y
L	H	H
L	L	L
H	X	Z

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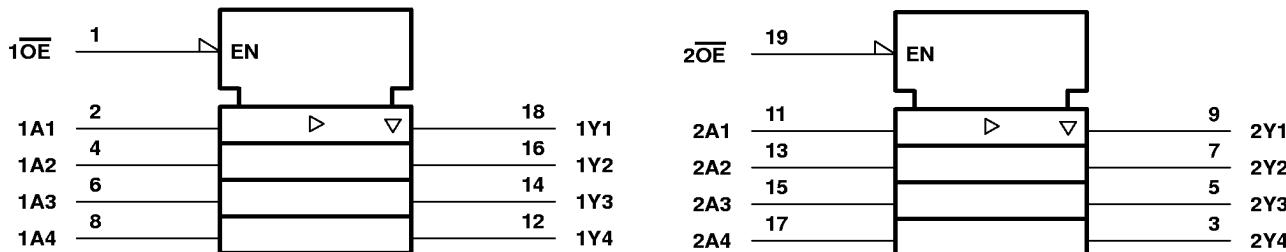
logic symbol†

† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)
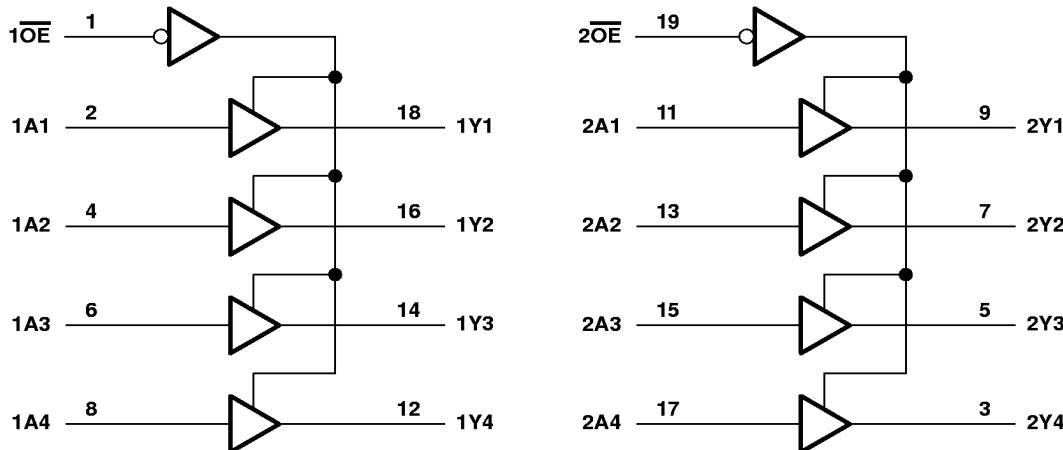
absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC} .... −0.5 V to 7 V
Input voltage range, V_I (see Note 1) .... −0.5 V to 7 V
Output voltage range, V_O (see Note 1) .... −0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$) .... −20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) .... ±20 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC}) .... ±25 mA
Continuous current through V_{CC} or GND .... ±75 mA
Package thermal impedance, θ_{JA} (see Note 2): DB package .... 115°C/W
 DGV package .... 146°C/W
 DW package .... 97°C/W
 N package .... 67°C/W
 PW package .... 128°C/W
Storage temperature range, T_{stg} .... −65°C to 150°C

‡ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

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recommended operating conditions (see Note 3)

		SN54AHCT244		SN74AHCT244		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	5.5	0	5.5	V
V_O	Output voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		−8		−8	mA
I_{OL}	Low-level output current		8		8	mA
T_A	Operating free-air temperature	−55	125	−40	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	$T_A = 25°C$			SN54AHCT244		SN74AHCT244		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V_{OH}	I_{OH} = −50 µA	4.5 V	4.4	4.5		4.4		4.4		V
	I_{OH} = −8 mA		3.94			3.8		3.8		
V_{OL}	I_{OL} = 50 µA	4.5 V			0.1		0.1		0.1	V
	I_{OL} = 8 mA				0.36		0.44		0.44	
I_{OZ}	V_O = V_{CC} or GND	5.5 V			±0.25		±2.5		±2.5	µA
I_I	V_I = V_{CC} or GND	5.5 V			±0.1		±1		±1	µA
I_{CC}	V_I = V_{CC} or GND, I_O = 0	5.5 V			4		40		40	µA
ΔI_{CC}†	One input at 3.4 V, Other inputs at V_{CC} or GND	5.5 V			1.35		1.5		1.5	mA
C_i	V_I = V_{CC} or GND	5 V		2.5	10				10	pF
C_o	V_O = V_{CC} or GND	5 V		3						pF

† This is the increase in supply current for each input at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	SN54AHCT244					UNIT
				T_A = 25°C			MIN	MAX	
				MIN	TYP	MAX			
t_{PLH}*	A	Y	C_L = 15 pF		5.4	7.4	1	8.5	ns
t_{PHL}*					5.4	7.4	1	8.5	
t_{PZH}*	$\overline{OE}$	Y	C_L = 15 pF		7.7	10.4	1	12	ns
t_{PZL}*					7.7	10.4	1	12	
t_{PHZ}*	$\overline{OE}$	Y	C_L = 15 pF		5	9.4	1	10	ns
t_{PLZ}*					5	9.4	1	10	
t_{PLH}	A	Y	C_L = 50 pF		5.9	8.4	1	9.5	ns
t_{PHL}					5.9	8.4	1	9.5	
t_{PZH}	$\overline{OE}$	Y	C_L = 50 pF		8.2	11.4	1	13	ns
t_{PZL}					8.2	11.4	1	13	
t_{PHZ}	$\overline{OE}$	Y	C_L = 50 pF		8.8	11.4	1	13	ns
t_{PLZ}					8.8	11.4	1	13	

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	SN74AHCT244					UNIT
				T_A = 25°C			MIN	MAX	
				MIN	TYP	MAX			
t_{PLH}	A	Y	C_L = 15 pF		5.4	7.4	1	8.5	ns
t_{PHL}					5.4	7.4	1	8.5	
t_{PZH}	$\overline{OE}$	Y	C_L = 15 pF		7.7	10.4	1	12	ns
t_{PZL}					7.7	10.4	1	12	
t_{PHZ}	$\overline{OE}$	Y	C_L = 15 pF		5	9.4	1	10	ns
t_{PLZ}					5	9.4	1	10	
t_{PLH}	A	Y	C_L = 50 pF		5.9	8.4	1	9.5	ns
t_{PHL}					5.9	8.4	1	9.5	
t_{PZH}	$\overline{OE}$	Y	C_L = 50 pF		8.2	11.4	1	13	ns
t_{PZL}					8.2	11.4	1	13	
t_{PHZ}	$\overline{OE}$	Y	C_L = 50 pF		8.8	11.4	1	13	ns
t_{PLZ}					8.8	11.4	1	13	
$t_{sk(o)}$†			C_L = 50 pF			1		1	ns

† Skew between any two outputs of the same package switching in the same direction

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noise characteristics, V_{CC} = 5 V, C_L = 50 pF, T_A = 25°C (see Note 4)

PARAMETER		SN74AHCT244			UNIT
		MIN	TYP	MAX	
$V_{OH(V)}$	Quiet output, minimum dynamic V_{OH}		4.1		V
$V_{IH(D)}$	High-level dynamic input voltage	2			V
$V_{IL(D)}$	Low-level dynamic input voltage			0.8	V

NOTE 4: Characteristics are for surface-mount packages only.

operating characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance	No load,	f = 1 MHz	8.2	pF

PARAMETER MEASUREMENT INFORMATION

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	V_{CC}
t_{PHZ}/t_{PZH}	GND
Open Drain	V_{CC}

From Output Under Test — Test Point
C_L (see Note A)
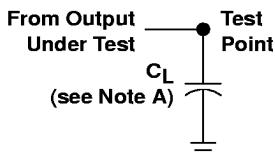
LOAD CIRCUIT FOR
TOTEM-POLE OUTPUTS

From Output Under Test — $R_L = 1 k\Omega$ — S1 — V_{CC} / Open / GND
C_L (see Note A)
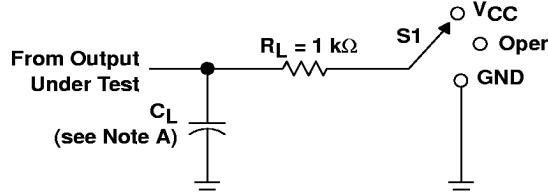
LOAD CIRCUIT FOR
3-STATE AND OPEN-DRAIN OUTPUTS

t_w — V_{CC} — 1.5 V — 1.5 V

Timing Input — 1.5 V — V_{CC} — 0 V — t_{su} — t_h — V_{CC}

Figure 1. Load Circuit and Voltage Waveforms